NSN 5961-01-419-6163

Demilitarization: Yes - demil/mli

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-419-6163 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.200 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 working peak reverse voltage and 1.5 forward voltage, peak **Current Rating Per Characteristic:** 500.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 12.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Nuclear Hardness Critical Feature:** Hardened **Precious Material And Location:** Terminal option silver or copper; terminal surface option gold or silver **Precious Material:** Gold and silver **Test Data Document:** 35351-171328 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**